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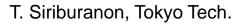
Outline

1 TOKYOTIECH PursuingExcellence

- Motivation
- Options for MM-wave Frequency Dividers

- CML Divider, Miller Divider, ILFD

- Proposed MM-wave Frequency Divider using Shunt-Series Peaking Technique
- Simulation Results
- Conclusion





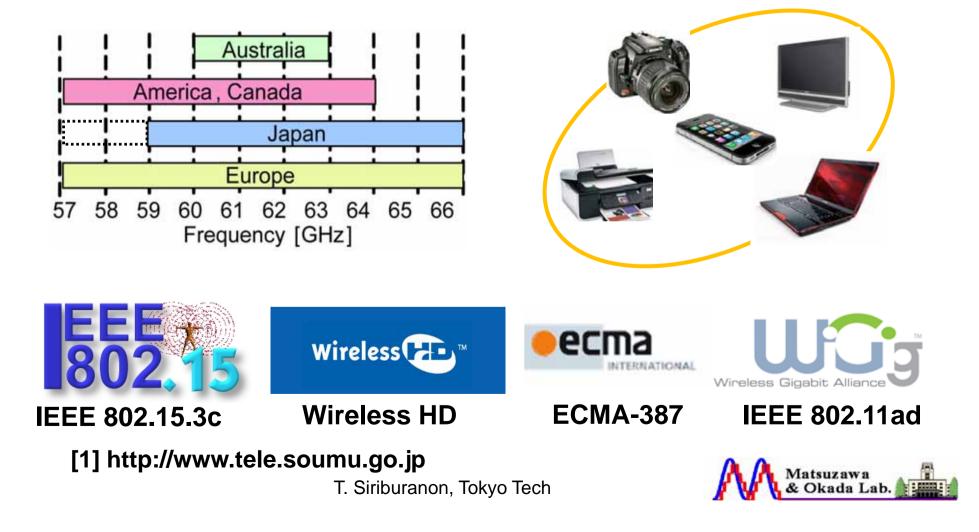
Motivation

• 9-GHz unlicensed bandwidth at 60 GHz

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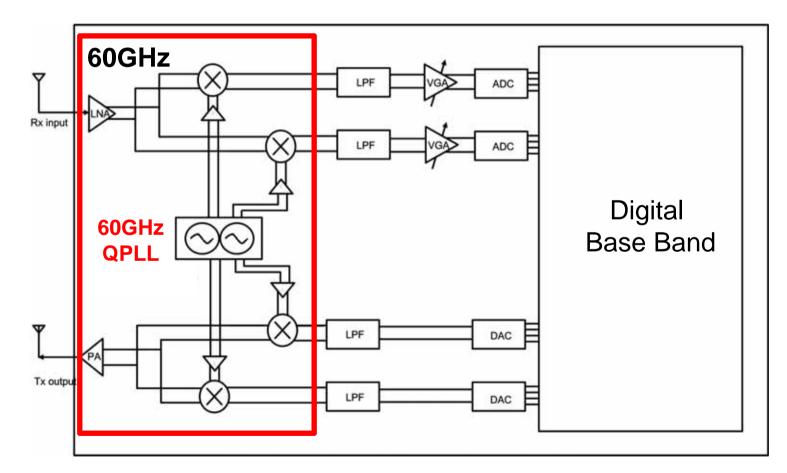
ΤΟΚΥ

Several Gbps wireless communication



Transceiver Architecture

- Direct Conversion for single chip implementation
 - Small area and lower power consumption

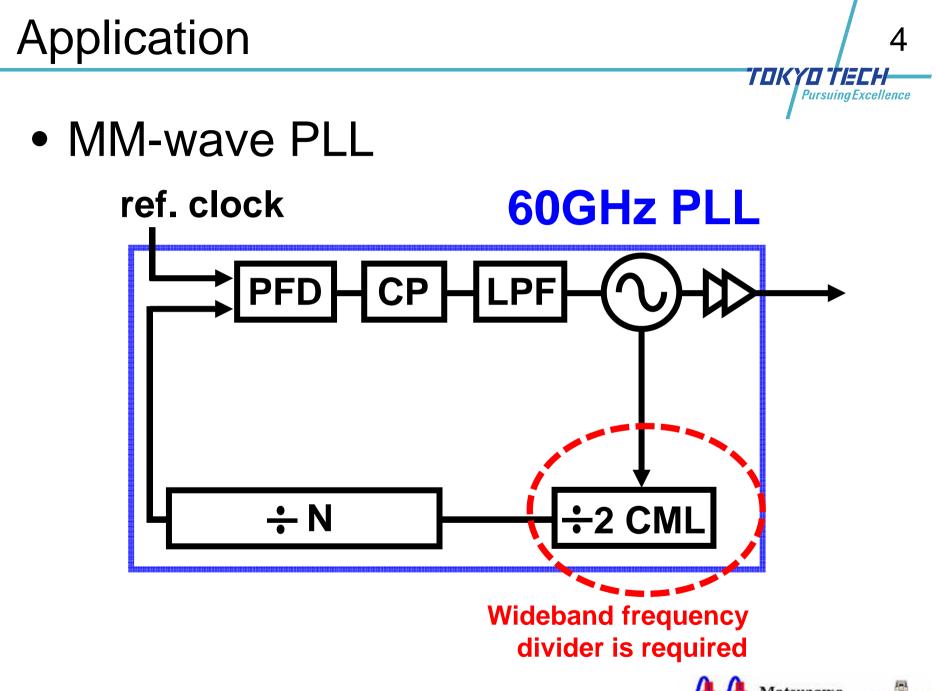


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Options for MM-wave Frequency Dividers

CML Static Divider

Wide frequency operating range
× Difficult to operate at MM-wave frequency

• Regenerative (Miller) Divider

Relatively larger Locking range compared to ILFD

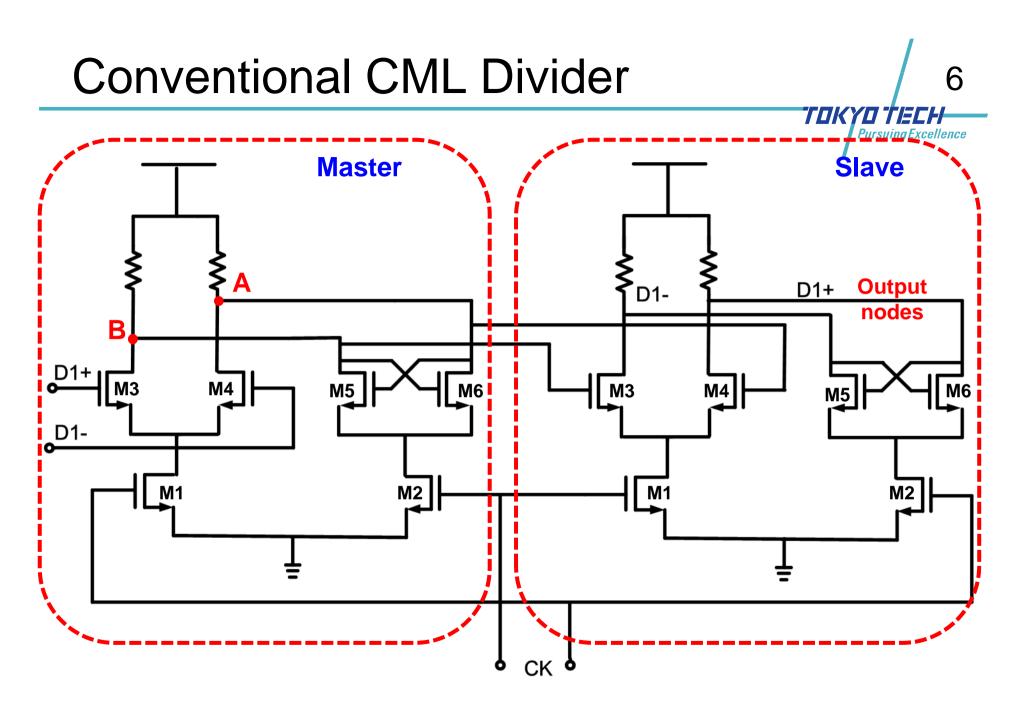
 Injection-Locked Frequency Divider (ILFD)

✓ High frequencies and Low power

× Narrow locking range



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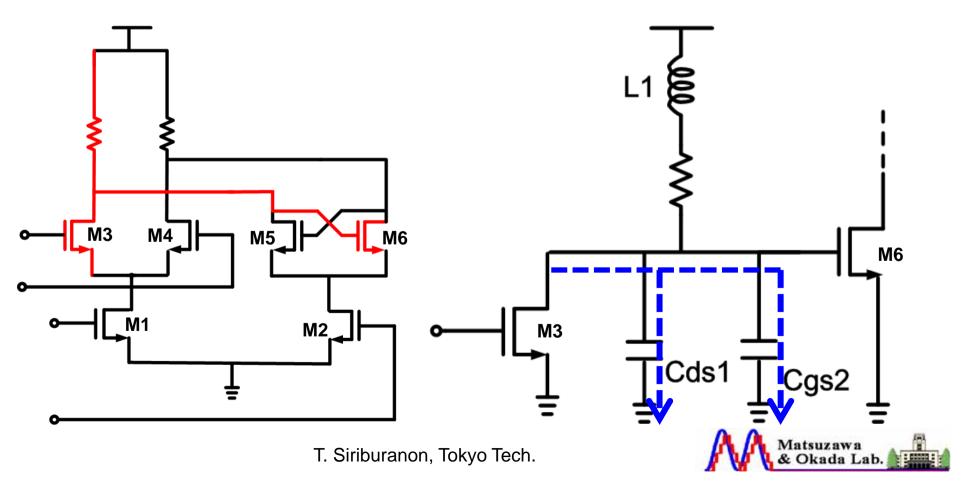
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Conventional Shunt Peaking



- L1 delays current flow to resistive branch
 - More current initially charges C = Cds1 + Cgs2
 - Reduces rise time



Shunt-Series Peaking Technique

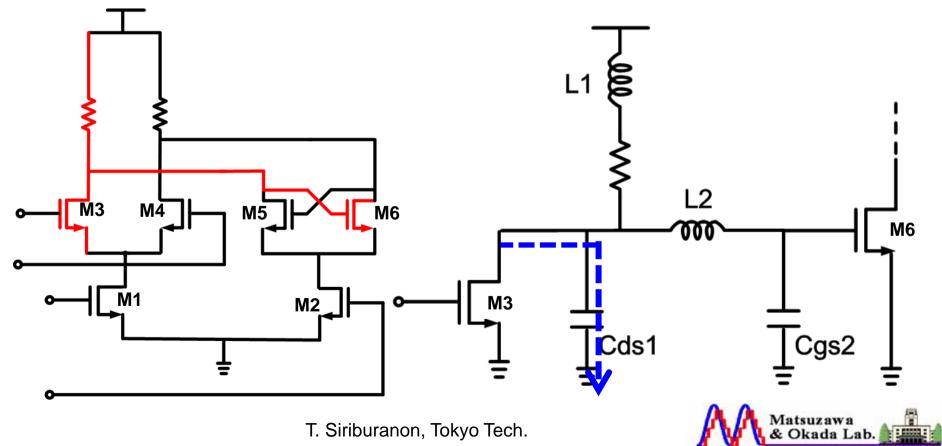
- Utilized in this proposed Frequency Divider
- L2 delays current to flow to the rest of the network.

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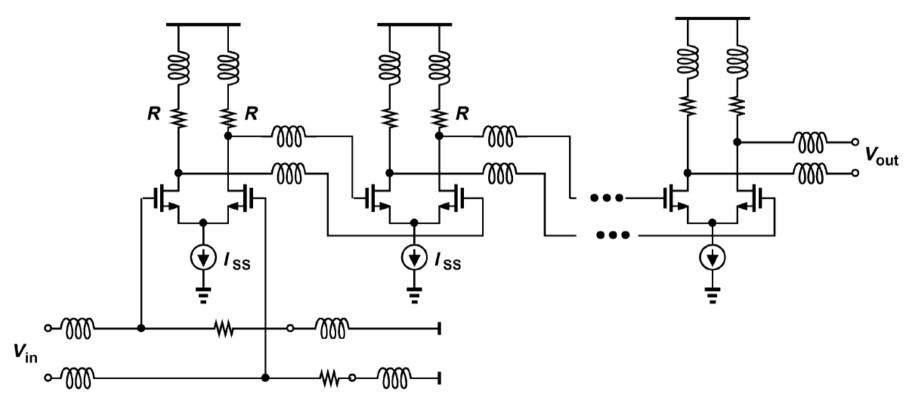
ΓΠΙ

- Only Cds1 is initially charged
- Reducing rise time at drain and increasing bandwidth



Shunt-series Application

• 5 differential stage applied in a broadband amplifier



Tech.	Gain	BW	Gain*BW	VDD	Power
0.18um CMOS	15dB	22GHz	124GHz	2.2	190mW

S. Galal and B. Razavi, JSSC, Dec. 2004.

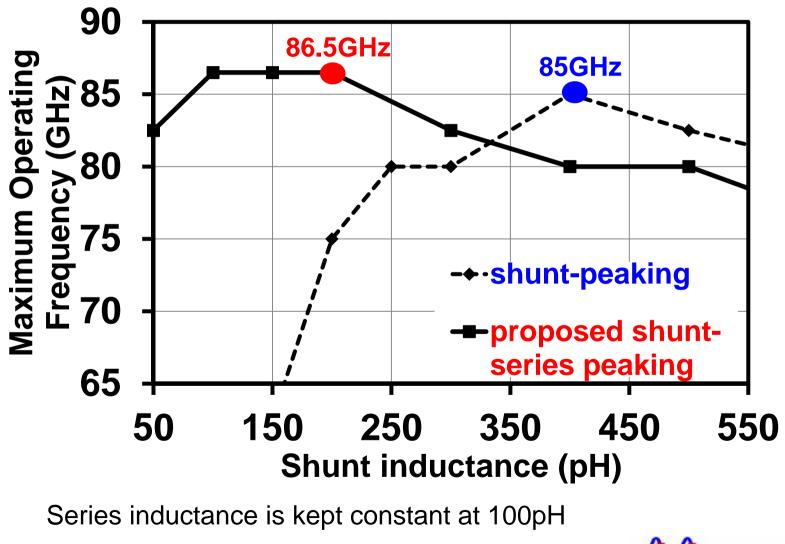
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Simulation Results (I)



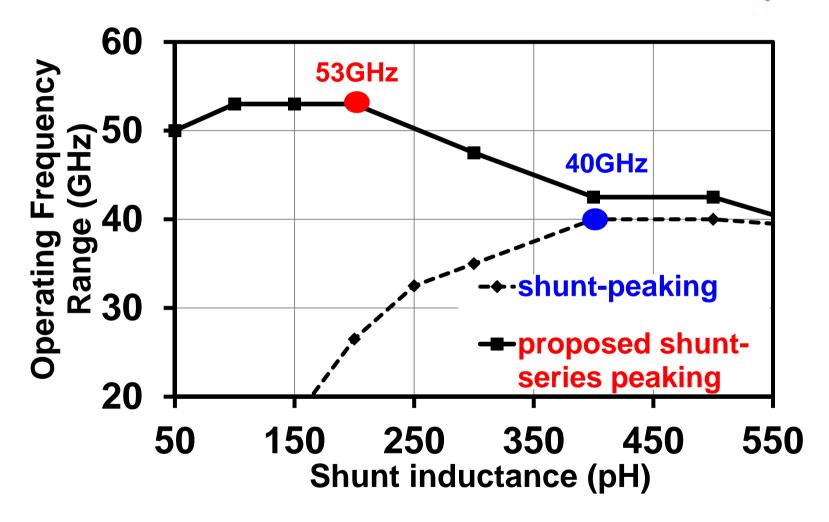
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Simulation Results (II)



Series inductance is kept constant at 100pH

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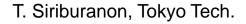
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	Туре	Operating Freq.	Range (GHz)	V supply	Power (mW)	Tech.
[1]	Bridged Shunt SFD	49-67	18	1.2	15.7	90 CMOS
[2]	SFD	70-85	15	1.2	19.2	65 GP CMOS
[3]	Pulsed- Latch SFD	21-37.8	16.8	1.8	22.5	130 CMOS
This	Shunt- Series SFD	33.5-86.5	53	1.2	22	65 CMOS

[1] ESSCIRC, 2010

[2] *CICC*, 2007

[3] ASSCC, 2007





Conclusion

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- Employing Shunt peaking, the divider can work from 45-85 GHz (40 GHz)
- Employing **Shunt-Series peaking**, the divider can work from 33.5-86.5 GHz (53GHz)
- Shunt-series architecture can increase operating frequency range by 13GHz (32.5%)

